

GaAs PHEMT MMIC LOW NOISE AMPLIFIER, 2.0 - 20.0 GHz

Typical Applications

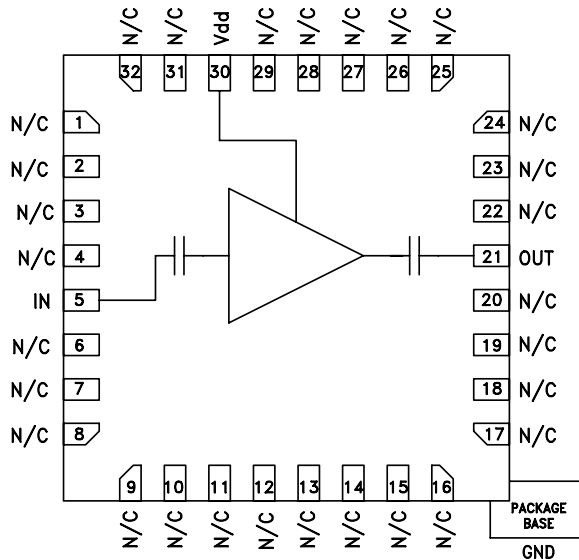
The HMC462LP5 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military EW, ECM & C³I
- Test Instrumentation
- Fiber Optics

Features

- Noise Figure: 2.5 dB @ 10 GHz
- Gain: 13 dB
- P1dB Output Power: +14.5 dBm @ 10 GHz
- Self-Biased: +5.0V @ 66 mA
- 50 Ohm Matched Input/Output
- 25 mm² Leadless SMT Package

Functional Diagram



General Description

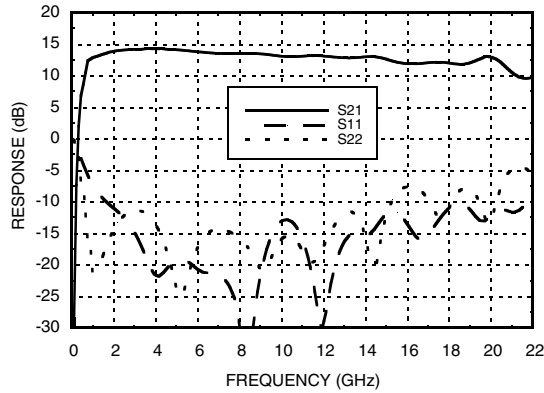
The HMC462LP5 is a GaAs MMIC PHEMT Low Noise Distributed Amplifier in a leadless 5 x 5 mm surface mount package which operates between 2 and 20 GHz. The self-biased amplifier provides 13 dB of gain, 2.5 to 3.5 dB noise figure and +14.5 dBm of output power at 1 dB gain compression while requiring only 66 mA from a single +5V supply. Gain flatness is excellent from 6 - 18 GHz making the HMC462LP5 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked.

Electrical Specifications, $T_A = +25^\circ C, V_{dd} = 5V$

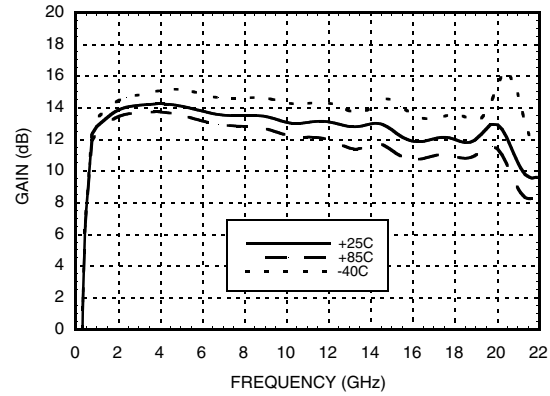
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		2.0 - 6.0		6.0 - 14.0		14.0 - 20.0				GHz
Gain	12	14		11	13		10	12		dB
Gain Flatness		±0.5			±0.5			±0.5		dB
Gain Variation Over Temperature		0.015	0.025		0.02	0.03		0.03	0.04	dB/°C
Noise Figure		3.0	4.0		2.5	4.0		4.0	6.0	dB
Input Return Loss		15			13			11		dB
Output Return Loss		12			12			8		dB
Output Power for 1 dB Compression (P1dB)	12	15		11	14		9	12		dBm
Saturated Output Power (Psat)		17			16			15		dBm
Output Third Order Intercept (IP3)		26			25			22		dBm
Supply Current (I _{dd}) (V _{dd} = 5V)		66			66			66		mA

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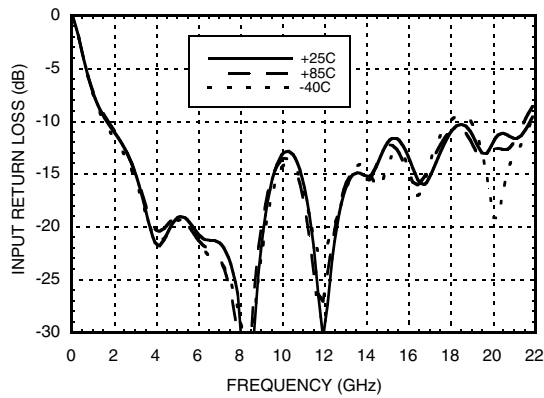
Gain & Return Loss



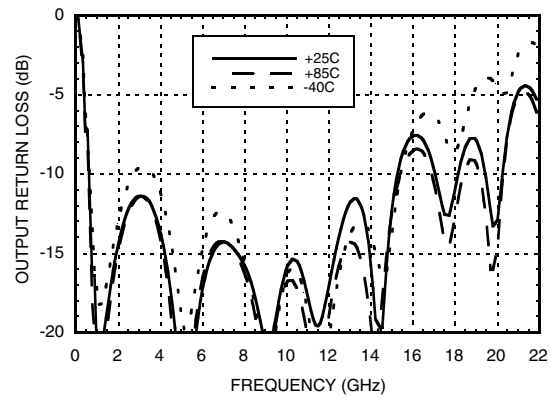
Gain vs. Temperature



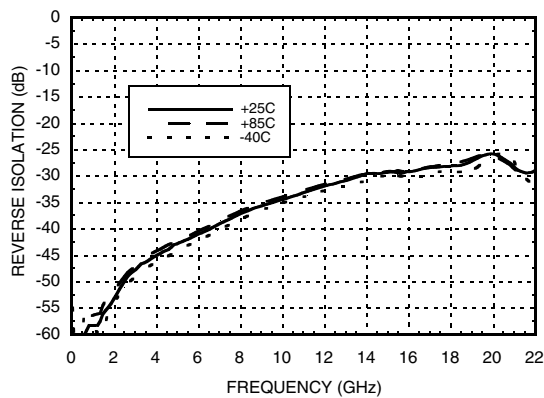
Input Return Loss vs. Temperature



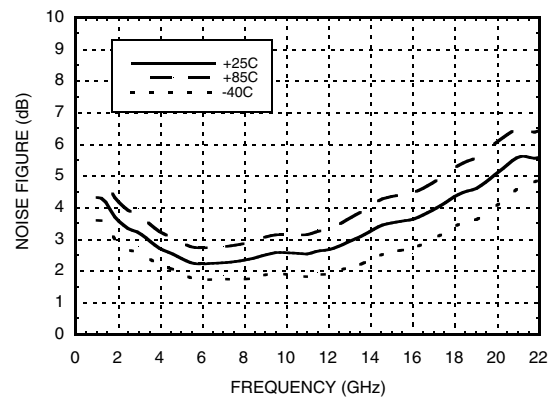
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature

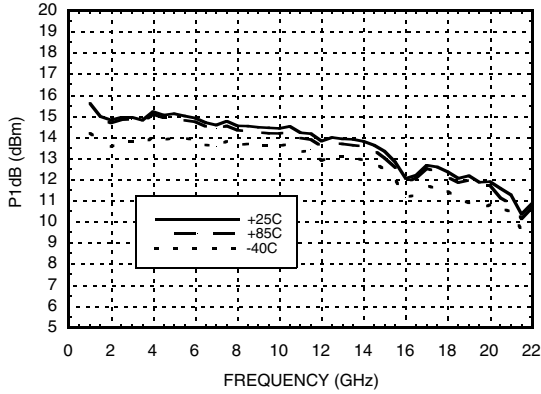


Noise Figure vs. Temperature

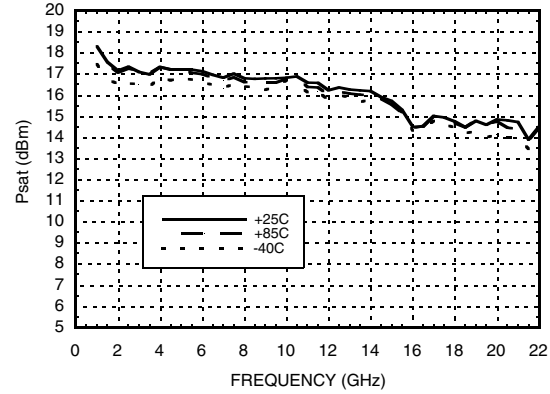


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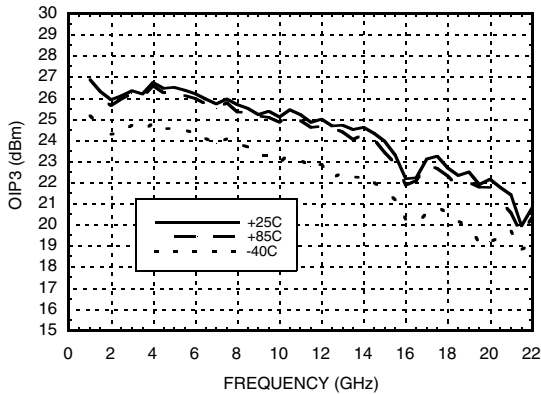
P1dB vs. Temperature



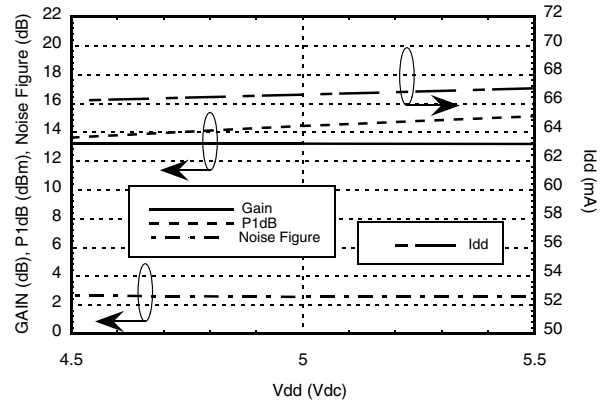
Psat vs. Temperature



Output IP3 vs. Temperature



Gain, Power, Noise Figure & Supply Current vs. Supply Voltage @ 10 GHz



Absolute Maximum Ratings

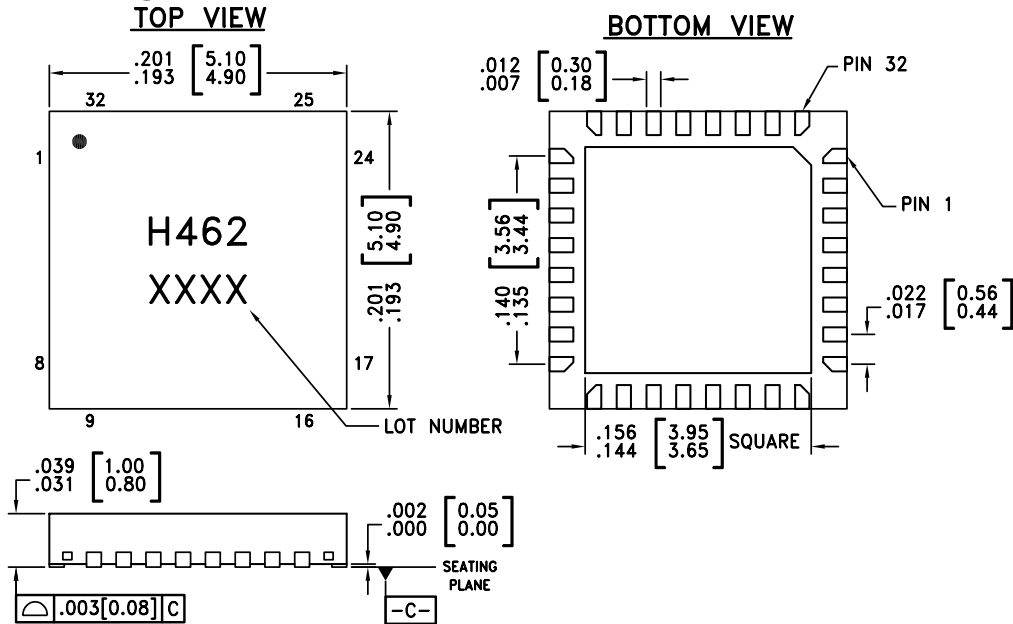
Drain Bias Voltage (Vdd)	+9.0 Vdc
RF Input Power (RFIn)(Vdd = +5.0 Vdc)	+23 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 50 mW/°C above 85 °C)	3.25 W
Thermal Resistance (channel to ground paddle)	20 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

Vdd (V)	Idd (mA)
+4.5	66
+5.0	67
+5.5	68
+7.5	71
+8.0	72
+8.5	73

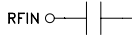

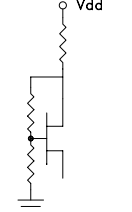

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Outline Drawing



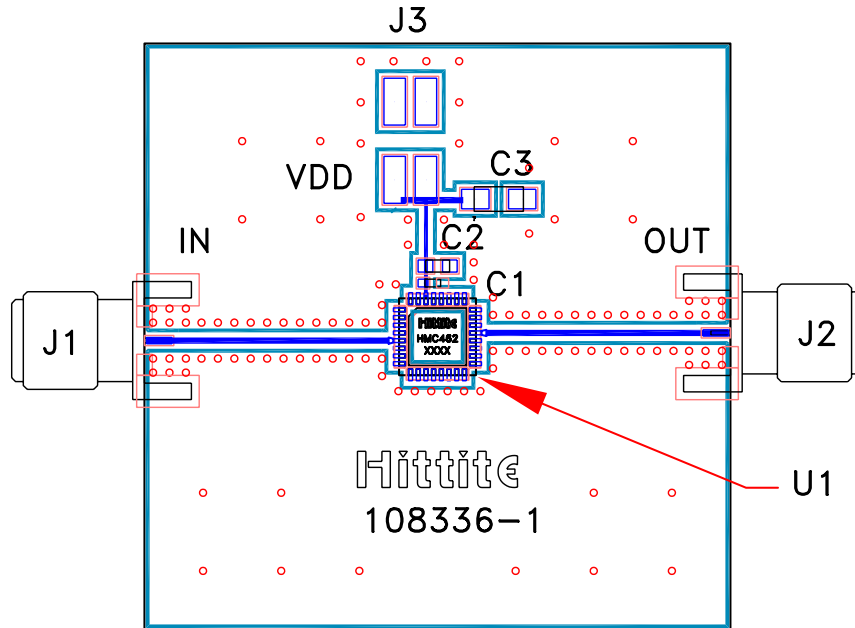
- NOTES:
1. ALL DIMENSIONS IN INCHES [MILLIMETERS]
 2. NO CONNECTION REQUIRED FOR UNLABELED BOND PADS
 3. DIE THICKNESS IS 0.004 (0.100)
 4. TYPICAL BOND PAD IS 0.004 (0.100) SQUARE
 5. BACKSIDE METALLIZATION: GOLD
 6. BACKSIDE METAL IS GROUND
 7. BOND PAD METALIZATION: GOLD

Pad Descriptions

Pad Number	Function	Description	Interface Schematic
5	RFIN	This pad is AC coupled and matched to 50 Ohms from 2.0 - 20.0 GHz.	
21	RFOUT	This pad is AC coupled and matched to 50 Ohms from 2.0 - 20.0 GHz.	
30	Vdd	Power supply voltage for the amplifier. External bypass capacitors are required.	
Ground Paddle	GND	Ground paddle must be connected to RF/DC ground.	
1-4, 6-20, 22-29, 31, 32	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	

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Evaluation PCB



List of Materials for Evaluation PCB 108338*

Item	Description
J1 - J2	PC Mount SMA Connector
J3	2 mm Molex Header
C1	100 pF Capacitor, 0402 Pkg.
C2	1000 pF Capacitor, 0603 Pkg.
C3	4.7 μF Capacitor, Tantalum
U1	HMC462LP5
PCB**	108336 Evaluation PCB
** Circuit Board Material: Rogers 4350	

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

* Reference this number when ordering complete evaluation PCB.



v00.0304

HMC462LP5

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Notes:

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AMPLIFIERS - SMT